

# Bias Resistor Transistor

## NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

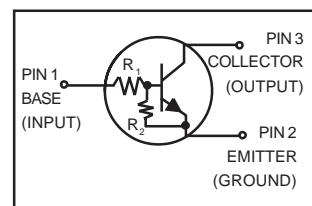
This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
  - Reduces Board Space
  - Reduces Component Count
  - The SC-70/SOT-323 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
  - Available in 8 mm embossed tape and reel
- Use the Device Number to order the 7 inch/3000 unit reel.
- Pb-Free package is available
  - S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

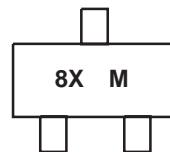
### DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

**LMUN5211T1G Series  
S-LMUN5211T1G Series**



**MARKINGDIAGRAM**



8x = Specific Device Code  
x = (See Marking Table)  
M= Date Code

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	202 (Note 1.) 310 (Note 2.) 1.6 (Note 1.) 2.5 (Note 2.)	mW mW/ $^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	618 (Note 1.) 403 (Note 2.)	$^\circ\text{C}/\text{W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	280 (Note 1.) 332 (Note 2.)	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**DEVICE MARKING RESISTOR VALUES AND ORDERING INFORMATION**

Device	Package	Marking	R1(K)	R2(K)	Shipping
LMUN5211T1G	SC-70/SOT-323	8A	10	10	3000/Tape&Reel
LMUN5211T3G	SC-70/SOT-323	8A	10	10	10000/Tape&Reel
LMUN5212T1G	SC-70/SOT-323	8B	22	22	3000/Tape&Reel
LMUN5212T3G	SC-70/SOT-323	8B	22	22	10000/Tape&Reel
LMUN5213T1G	SC-70/SOT-323	8C	47	47	3000/Tape&Reel
LMUN5213T3G	SC-70/SOT-323	8C	47	47	10000/Tape&Reel
LMUN5214T1G	SC-70/SOT-323	8D	10	47	3000/Tape&Reel
LMUN5214T3G	SC-70/SOT-323	8D	10	47	10000/Tape&Reel
LMUN5215T1G(Note 3)	SC-70/SOT-323	8E	10	$\infty$	3000/Tape&Reel
LMUN5215T3G	SC-70/SOT-323	8E	10	$\infty$	10000/Tape&Reel
LMUN5216T1G(Note 3)	SC-70/SOT-323	8F	4.7	$\infty$	3000/Tape&Reel
LMUN5216T3G	SC-70/SOT-323	8F	4.7	$\infty$	10000/Tape&Reel
LMUN5230T1G(Note 3)	SC-70/SOT-323	8G	1	1	3000/Tape&Reel
LMUN5230T3G	SC-70/SOT-323	8G	1	1	10000/Tape&Reel
LMUN5231T1G(Note 3)	SC-70/SOT-323	8H	2.2	2.2	3000/Tape&Reel
LMUN5231T3G	SC-70/SOT-323	8H	2.2	2.2	10000/Tape&Reel
LMUN5232T1G(Note 3)	SC-70/SOT-323	8J	4.7	4.7	3000/Tape&Reel
LMUN5232T3G	SC-70/SOT-323	8J	4.7	4.7	10000/Tape&Reel
LMUN5233T1G(Note 3)	SC-70/SOT-323	8K	4.7	47	3000/Tape&Reel
LMUN5233T3G	SC-70/SOT-323	8K	4.7	47	10000/Tape&Reel
LMUN5234T1G(Note 3)	SC-70/SOT-323	8L	22	47	3000/Tape&Reel
LMUN5234T3G	SC-70/SOT-323	8L	22	47	10000/Tape&Reel
LMUN5235T1G(Note 3)	SC-70/SOT-323	8M	2.2	47	3000/Tape&Reel
LMUN5235T3G	SC-70/SOT-323	8M	2.2	47	10000/Tape&Reel
LMUN5236T1G(Note 3)	SC-70/SOT-323	8N	100	100	3000/Tape&Reel
LMUN5236T3G	SC-70/SOT-323	8N	100	100	10000/Tape&Reel
LMUN5237T1G(Note 3)	SC-70/SOT-323	8P	47	22	3000/Tape&Reel
LMUN5237T3G	SC-70/SOT-323	8P	47	22	10000/Tape&Reel

3. New devices. Updated curves to follow in subsequent data sheets.



## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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## OFF CHARACTERISTICS

Collector-Base Cutoff Current ( $V_{CB} = 50$ V, $I_E = 0$ )	$I_{CBO}$	—	—	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50$ V, $I_B = 0$ )	$I_{CEO}$	—	—	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0$ V, $I_C = 0$ )	LMUN5211T1G	$I_{EBO}$	—	—	0.5
	LMUN5212T1G		—	—	0.2
	LMUN5213T1G		—	—	0.1
	LMUN5214T1G		—	—	0.2
	LMUN5215T1G		—	—	0.9
	LMUN5216T1G		—	—	1.9
	LMUN5230T1G		—	—	4.3
	LMUN5231T1G		—	—	2.3
	LMUN5232T1G		—	—	1.5
	LMUN5233T1G		—	—	0.18
	LMUN5234T1G		—	—	0.13
	LMUN5235T1G		—	—	0.2
	LMUN5236T1G		—	—	0.05
	LMUN5237T1G		—	—	0.13
Collector-Base Breakdown Voltage ( $I_C = 10$ $\mu$ A, $I_E = 0$ )	$V_{(BR)CBO}$	50	—	—	Vdc
Collector-Emitter Breakdown Voltage (Note 4.) ( $I_C = 2.0$ mA, $I_B = 0$ )	$V_{(BR)CEO}$	50	—	—	Vdc

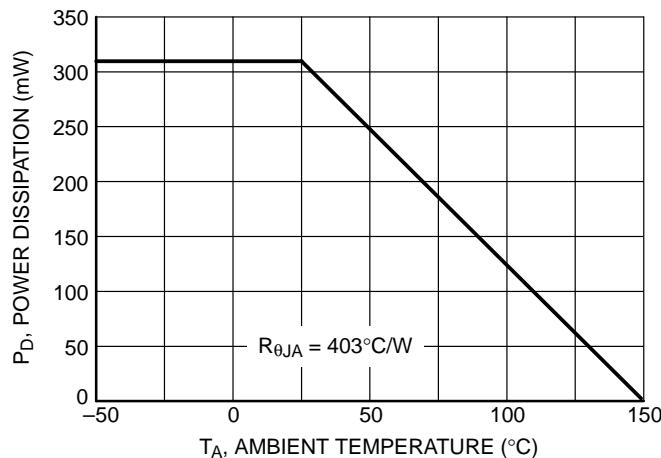
## **ON CHARACTERISTICS (Note 4.)**

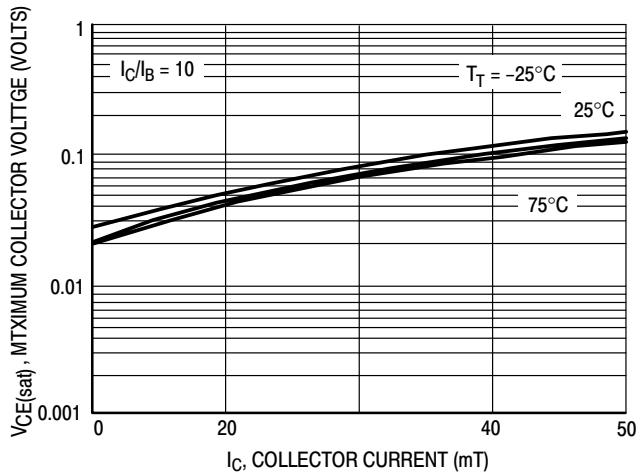
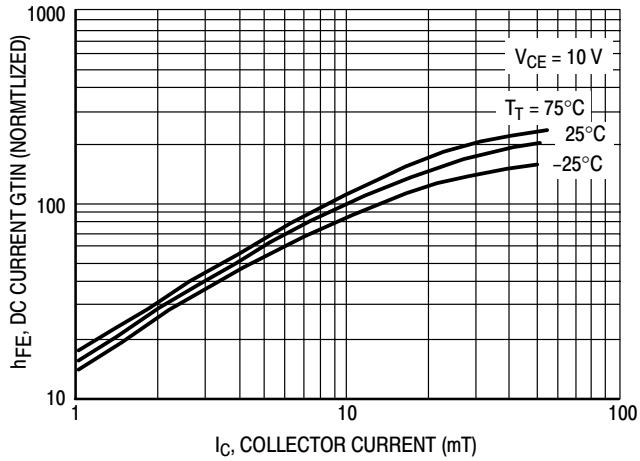
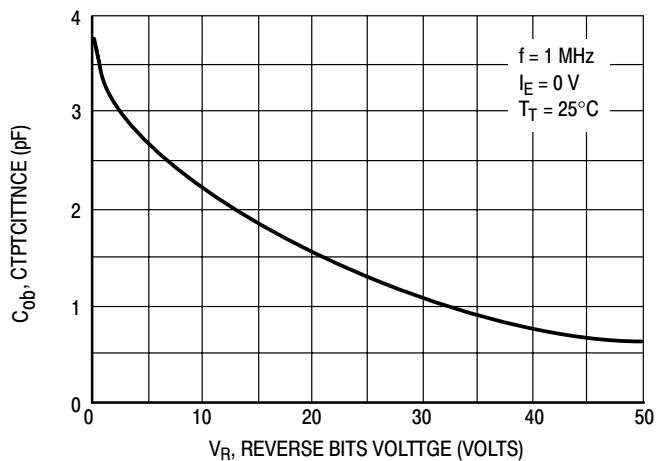
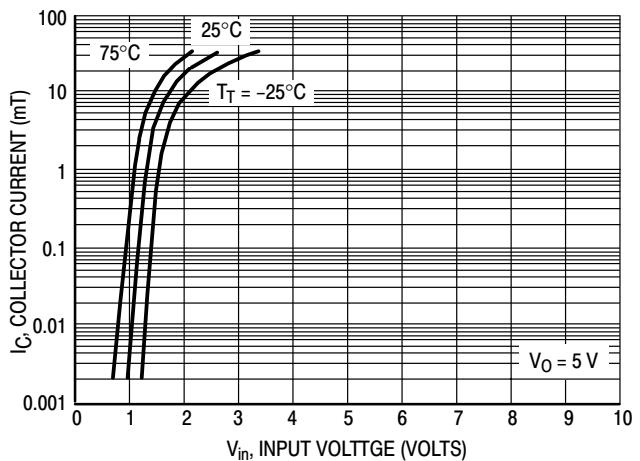
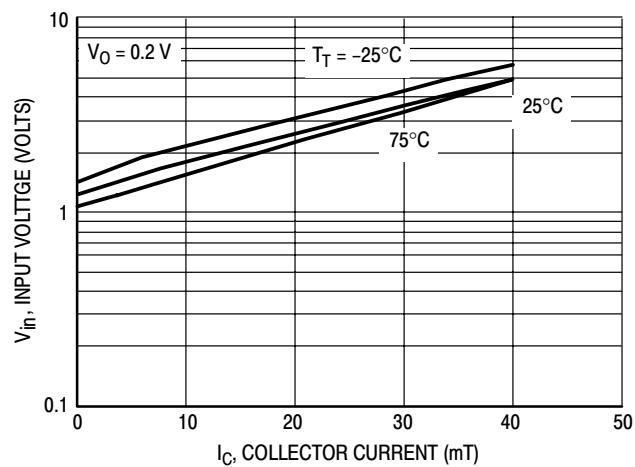
DC Current Gain ( $V_{CE} = 10$ V, $I_C = 5.0$ mA)	LMUN5211T1G LMUN5212T1G LMUN5213T1G LMUN5214T1G LMUN5215T1G LMUN5216T1G LMUN5230T1G LMUN5231T1G LMUN5232T1G LMUN5233T1G LMUN5234T1G LMUN5235T1G LMUN5236T1G LMUN5237T1G	$h_{FE}$	35 60 80 80 160 160 3.0 8.0 15 80 80 80 80 80	60 100 140 140 350 350 5.0 15 30 200 150 140 150 140	220 — 320 — — — — — — — — — — — —	
Collector-Emitter Saturation Voltage ( $I_C = 10$ mA, $I_B = 0.3$ mA) ( $I_C = 10$ mA, $I_B = 5$ mA) LMUN5230T1/LMUN5231T1 ( $I_C = 10$ mA, $I_B = 1$ mA) LMUN5215T1/LMUN5216T1/ LMUN5232T1/LMUN5233T1/LMUN5234T1	$V_{CE(sat)}$	—	—	—	0.25	Vdc
Output Voltage (on) ( $V_{CC} = 5.0$ V, $V_B = 2.5$ V, $R_L = 1.0$ k $\Omega$ )	LMUN5211T1G LMUN5212T1G LMUN5214T1G LMUN5215T1G LMUN5216T1G LMUN5230T1G LMUN5231T1G LMUN5232T1G LMUN5233T1G LMUN5234T1G LMUN5235T1G	$V_{OL}$	— — — — — — — — — — —	— — — — — — — — — — —	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	Vdc
( $V_{CC} = 5.0$ V, $V_B = 3.5$ V, $R_L = 1.0$ k $\Omega$ ) ( $V_{CC} = 5.0$ V, $V_B = 5.5$ V, $R_L = 1.0$ k $\Omega$ ) ( $V_{CC} = 5.0$ V, $V_B = 4.0$ V, $R_L = 1.0$ k $\Omega$ )	LMUN5213T1G LMUN5236T1G LMUN5237T1G	— — —	— — —	— — —	0.2 0.2 0.2	

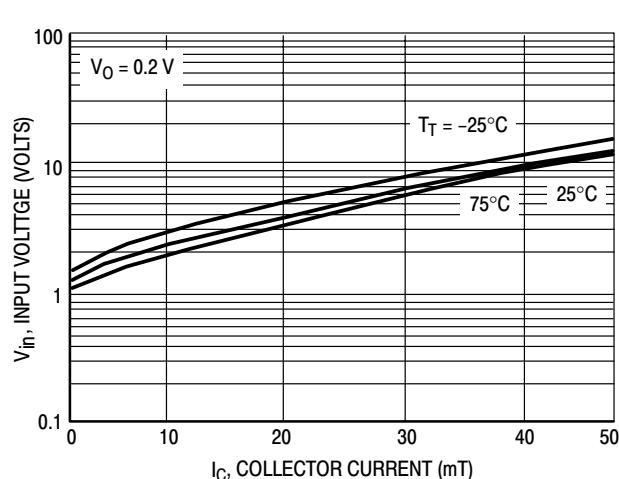
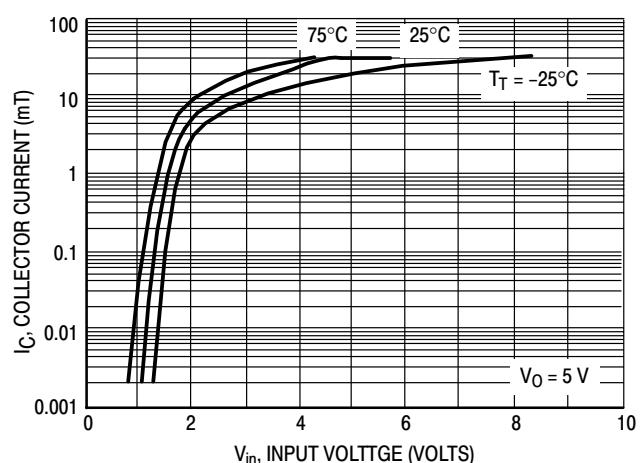
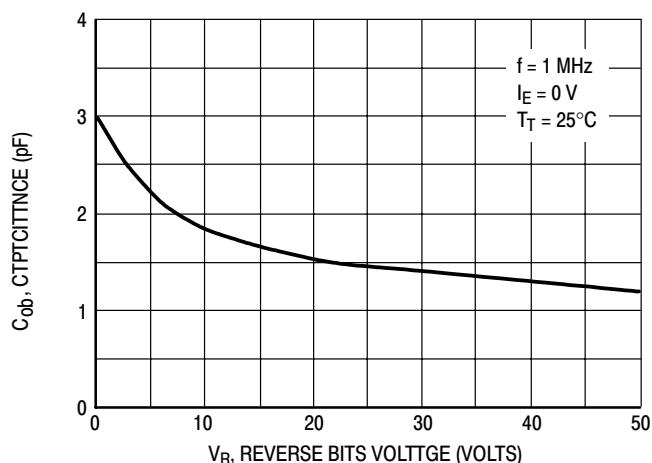
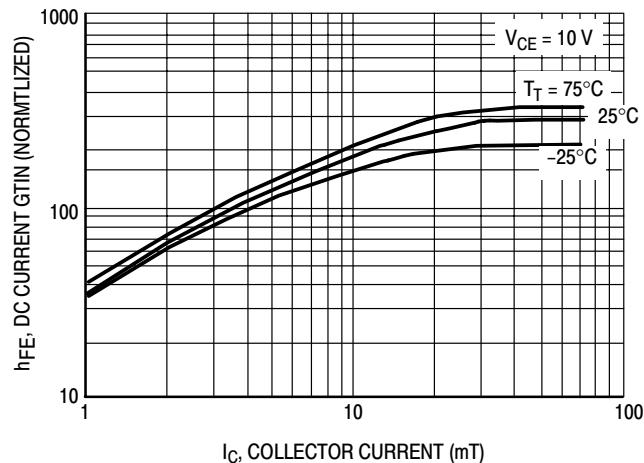
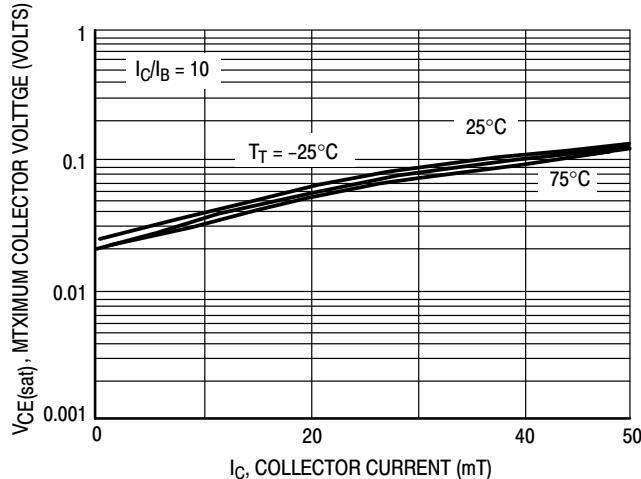
#### 4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

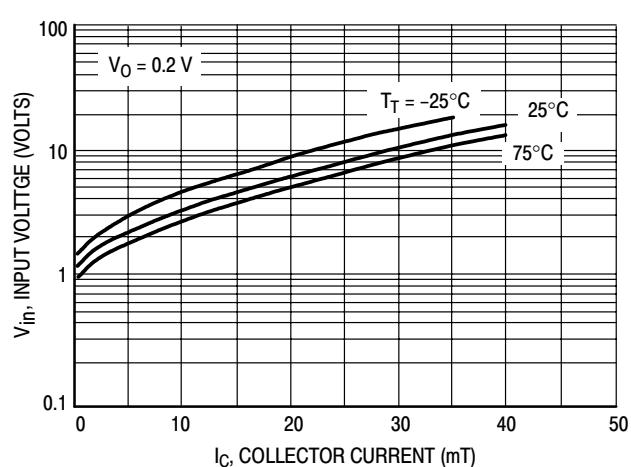
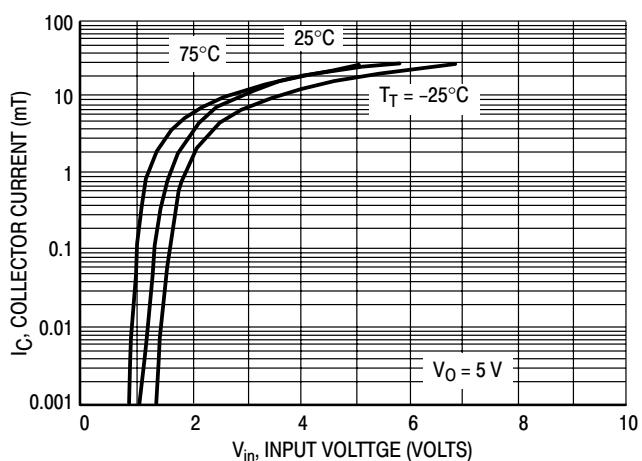
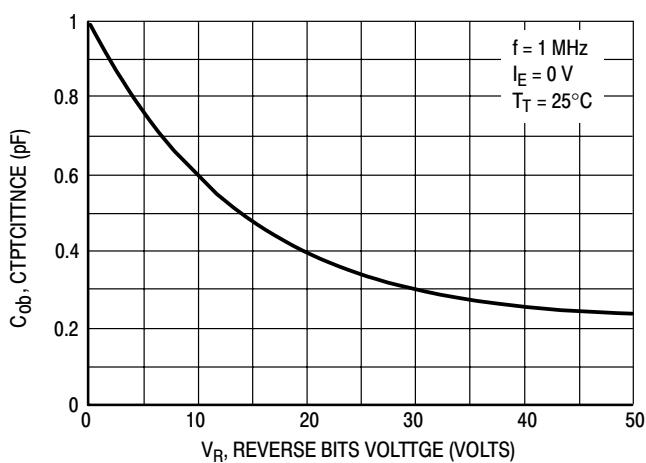
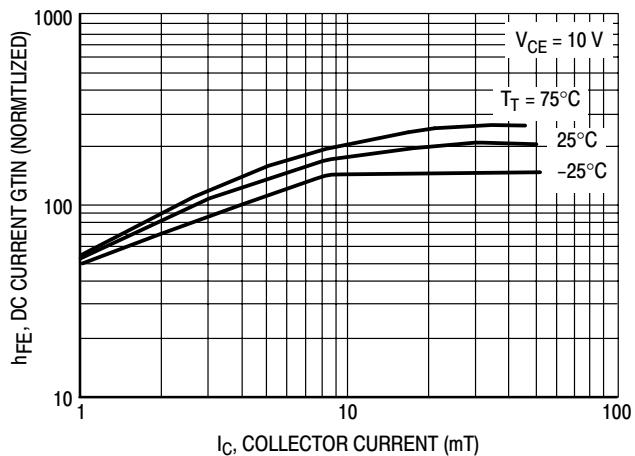
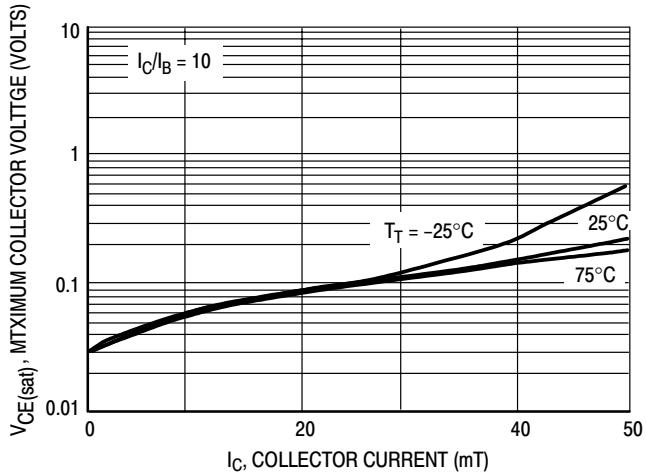
**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b> (Note 5.) (Continued)					
Output Voltage (off) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 0.5 \text{ V}$ , $R_L = 1.0 \text{ k}\Omega$ ) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 0.050 \text{ V}$ , $R_L = 1.0 \text{ k}\Omega$ ) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 0.25 \text{ V}$ , $R_L = 1.0 \text{ k}\Omega$ )	$V_{OH}$	4.9	—	—	Vdc
Input Resistor	$R_1$	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 1.54 70 32.9	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 2.2 100 47	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 2.86 130 61.1	k $\Omega$
Resistor Ratio	$R_1/R_2$	0.8 0.17 — 0.8 0.055 0.38 0.038 1.7	1.0 0.21 — 1.0 0.1 0.47 0.047 2.1	1.2 0.25 — 1.2 0.185 0.56 0.056 2.6	

5. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%

**Figure 1. Derating Curve**

**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5211T1G**

**Figure 2.  $V_{CE(sat)}$  versus  $I_C$** 

**Figure 3. DC Current Gain**

**Figure 4. Output Capacitance**

**Figure 5. Output Current versus Input Voltage**

**Figure 6. Input Voltage versus Output Current**

**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5212T1G**


**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5213T1G**


**LMUN5211T1G Series ;S-LMUN5211T1G Series**  
**TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5214T1G**

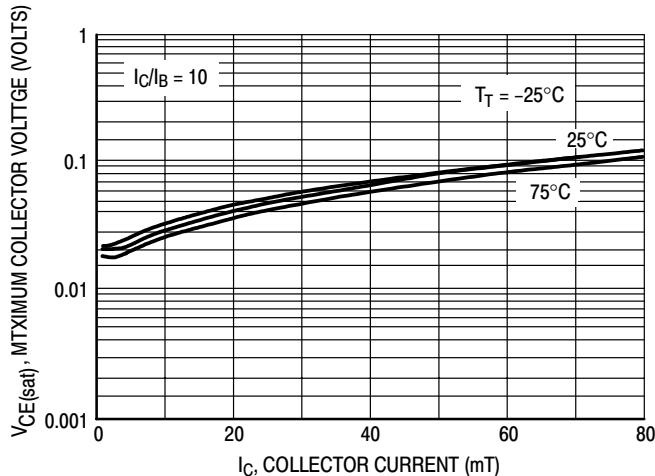


Figure 17.  $V_{CE(sat)}$  versus  $I_C$

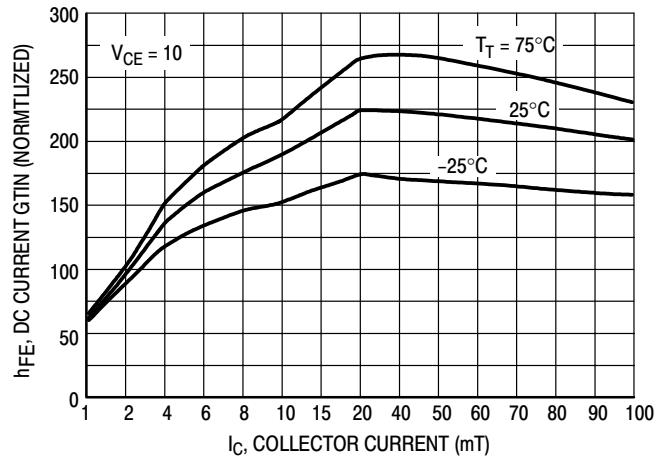


Figure 18. DC Current Gain

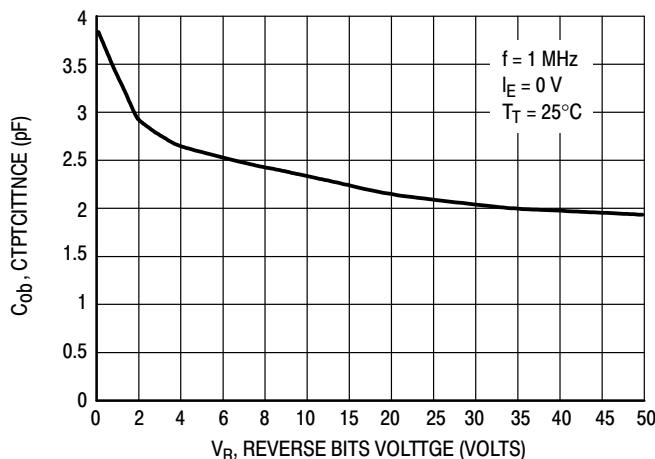


Figure 19. Output Capacitance

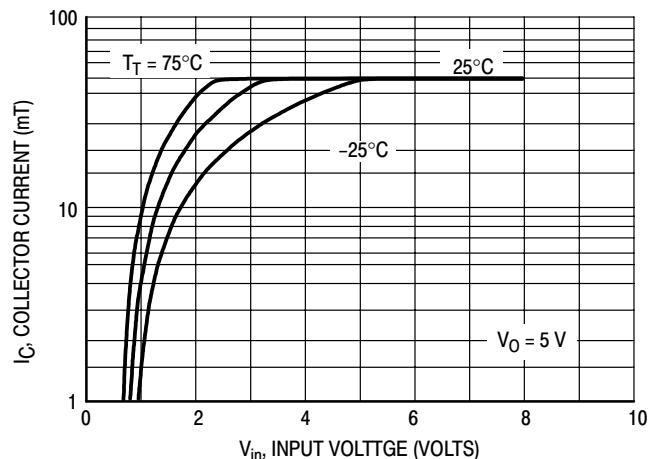


Figure 20. Output Current versus Input Voltage

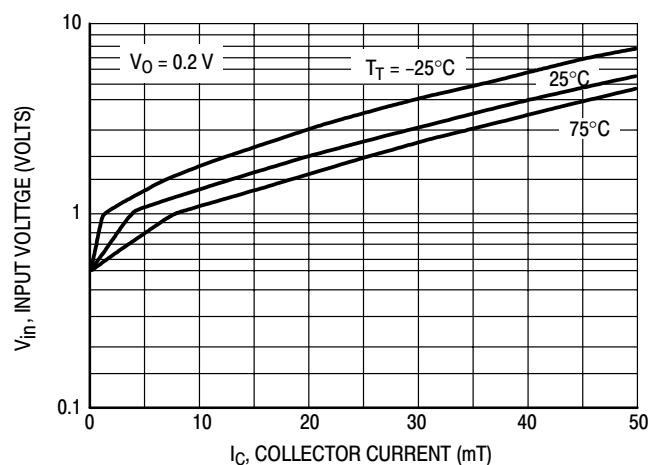
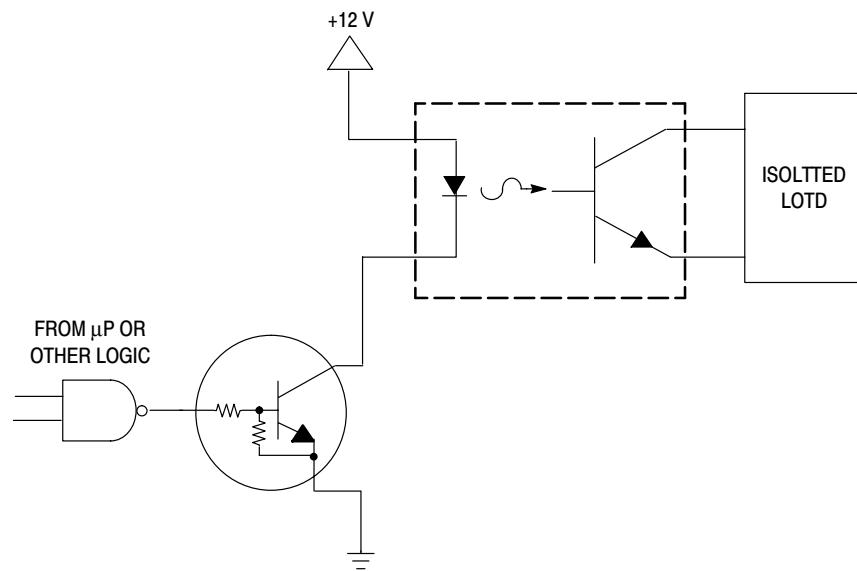
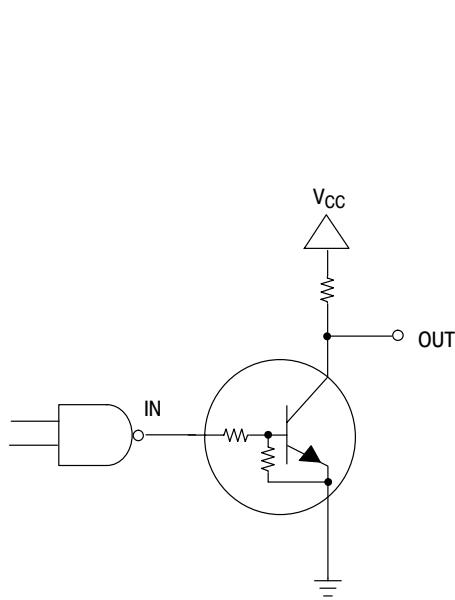


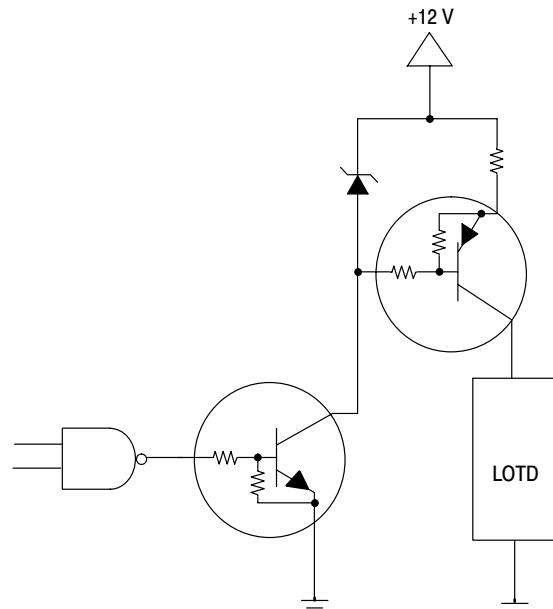
Figure 21. Input Voltage versus Output Current

**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**TYPICAL APPLICATIONS FOR NPN BRTs**


**Figure 22. Level Shifter: Connects 12 or 24 Volt Circuits to Logic**



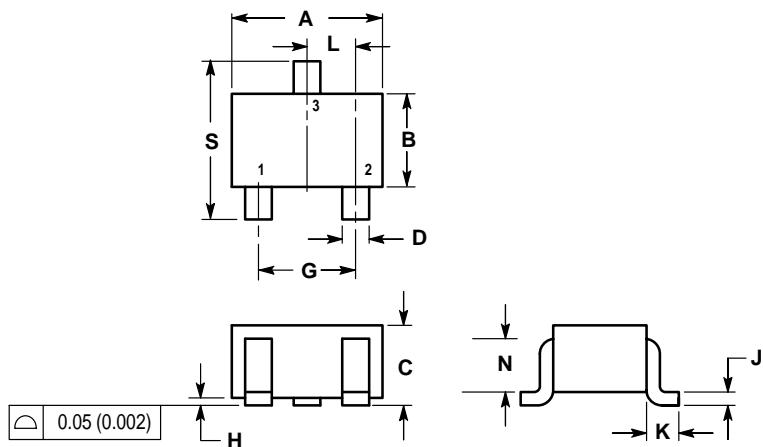
**Figure 23. Open Collector Inverter:  
Inverts the Input Signal**



**Figure 24. Inexpensive, Unregulated Current Source**

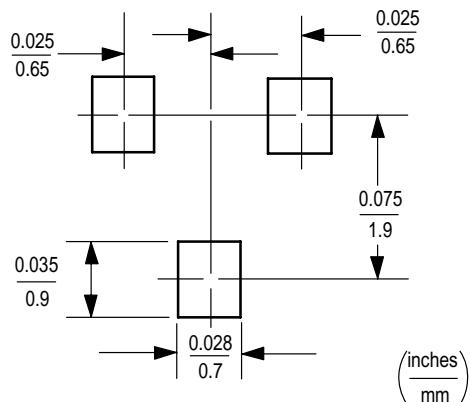
**LMUN5211T1G Series ;S-LMUN5211T1G Series**
**SC-70 / SOT-323**
**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017	REF	0.425	REF
L	0.026	BSC	0.650	BSC
N	0.028	REF	0.700	REF
S	0.079	0.095	2.00	2.40

- PIN 1. BASE  
 2. Emitter  
 3. Collector



# X-ON Electronics

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[NSVB1706DMW5T1G](#) [NSBC143EDP6T5G](#) [RN2101,LF\(CT](#) [NSBA144WDXV6T1G](#) [DTA115TET1G](#) [NSBC115TDP6T5G](#)